

Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT186A (TO-220F) plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

2. Features and benefits

- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- High noise immunity
- Triggering in all four quadrants
- Isolated package

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| able 1. Q | uick reference data | | | | | | |
|------------------|--|--|-------------|---|------|------|----|
| Symbol | Parameter | Conditions | Values | | | Unit | |
| Absolute | maximum rating | | | | | | |
| V_{DRM} | repetitive peak off-state voltage | | | 6 | 600 | | V |
| $I_{T(RMS)}$ | RMS on-state current | full sine wave; T _h ≤ 38 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u> | 16 | | | A | |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | 155 | | | A | |
| Symbol | Parameter | Conditions | Min Typ Max | | Unit | | |
| Static ch | aracteristics | | | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | | - | 5 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 8 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | | - | 10 | 35 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u> | | - | 22 | 70 | mA |

5. Pinning information

| Table 2. I | Pinning infor | mation | | |
|------------|---------------|-------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | |
| 2 | T2 | main terminal 2 | | Ν |
| 3 | G | gate | | |
| mb | n.c. | mounting base; isolated | | G sym051 |
| | | | | |
| | | | | |
| | | | | |
| | | | 1 2 3 | |

6. Ordering information

| Table 3. Ordering information | | | | | | |
|-------------------------------|---------|--|---------|--|--|--|
| Type number | Package | e | | | | |
| | Name | Description | Version | | | |
| BT139X-600 | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | |

7. Marking

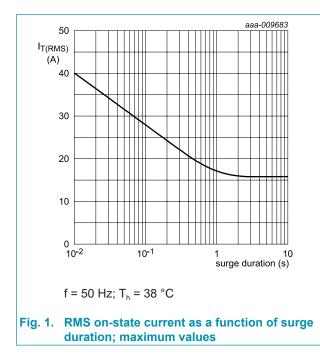
| Table 4. Marking codes | | | | | | |
|------------------------|---------------|--|--|--|--|--|
| Type number | Marking codes | | | | | |
| BT139X-600 | BT139X-600 | | | | | |

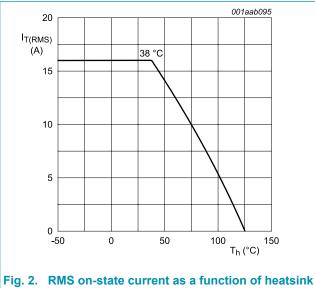
8. Limiting values

Table 5. Limiting values

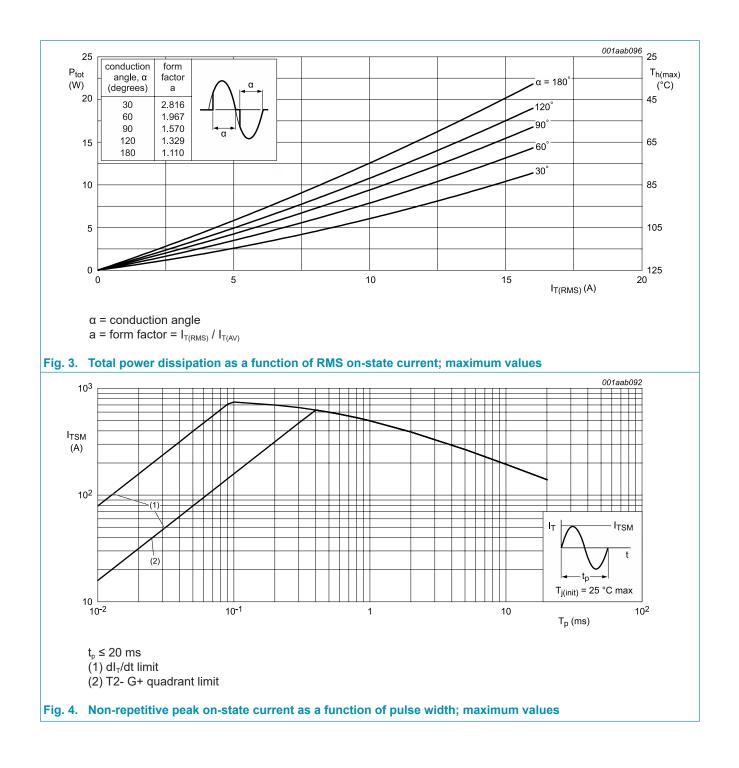
In accordance with the Absolute Maximum Rating System (IEC 60134).

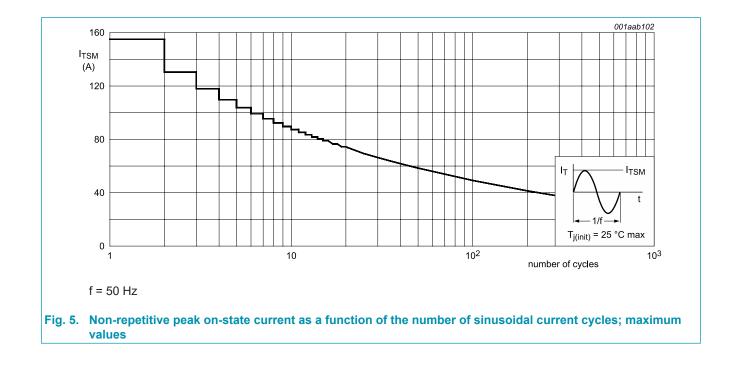
| Symbol | Parameter | Conditions | Values | Unit |
|---------------------|--|---|------------|------------------|
| V_{DRM} | repetitive peak off-state voltage | | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _h ≤ 38 °C; <u>Fig 1</u> ; <u>Fig 2</u> ; <u>Fig 3</u> | 16 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5 | 155 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | 170 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | 120 | A ² s |
| dl _T /dt | rate of rise of on-state current | I _G = 70 mA; T2+ G+ | 50 | A/µs |
| | | I _G = 70 mA; T2+ G- | 50 | A/µs |
| | | I _G = 70 mA; T2- G- | 50 | A/µs |
| | | I _G = 140 mA; T2- G+ | 10 | A/µs |
| I _{GM} | peak gate current | | 2 | А |
| P _{GM} | peak gate power | | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | 0.5 | W |
| T _{stg} | storage temperature | | -40 to 150 | °C |
| T _j | junction temperature | | 125 | °C |





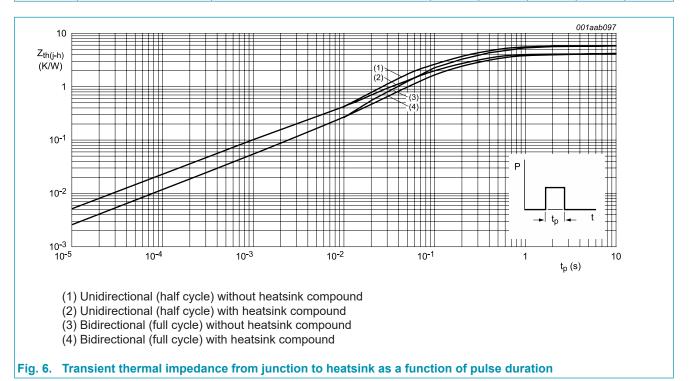
temperature; maximum values





9. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|--|-----|-----|-----|------|
| $R_{th(j-h)}$ | thermal resistance from junction to heatsink | full or half cycle; with heatsink compound; Fig 6 | - | - | 4 | K/W |
| | | full or half cycle; without heatsink compound; Fig 6 | - | - | 5.5 | K/W |
| $R_{\text{th(j-a)}}$ | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



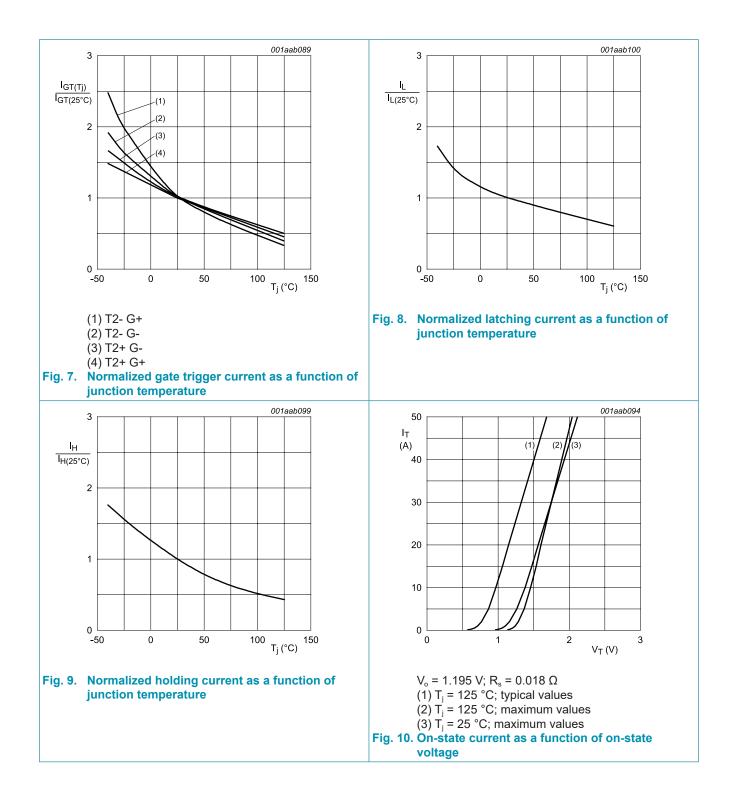
10. Isolation characteristics

| Table 7. Isc | lation characteristics | | | | | |
|------------------------|------------------------|---|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink; f = 1 MHz; T_h = 25 °C | - | 10 | - | pF |

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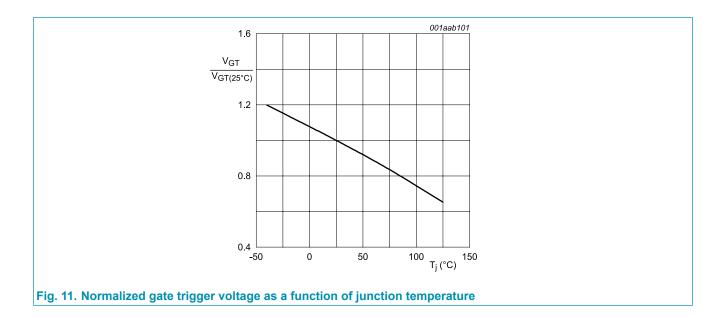
11. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|--|---|------|-----|-----|------|
| | aracteristics | | | | | |
| I _{GT} | gate trigger current | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$ | - | 5 | 35 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7 | - | 8 | 35 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7 | - | 10 | 35 | mA |
| | | $V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 7</u> | - | 22 | 70 | mA |
| l | latching current | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 40 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | 20 | 60 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u> | - | 8 | 40 | mA |
| | | $V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 8</u> | - | 10 | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 6 | 45 | mA |
| V _T | on-state voltage | I _T = 20 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.2 | 1.6 | V |
| V _{gt} | gate trigger voltage | $V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C};$ Fig. 11 | - | 0.7 | 1 | V |
| | | V_{D} = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic | characteristics | · · · · | | | | |
| dV _D /dt | rate of rise of off-state voltage | $V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; (V_{DM} = 67\% \text{ of } V_{DRM});$ exponential waveform; gate open circuit | 200 | 250 | - | V/µs |
| dV _{com} /dt | rate of change of commutating voltage | $V_D = 400 \text{ V}; \text{ T}_j = 95 \text{ °C}; \text{ I}_T = 16 \text{ A};$ $dI_{\text{com}}/dt = 7.2 \text{ A/ms};$ gate open circuit | 10 | 20 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | $V_{\rm D}$ = 600 V; I _{TM} = 20 A; I _G = 0.1 A; dI _G /dt = 5 A/µs | - | 2 | - | μs |

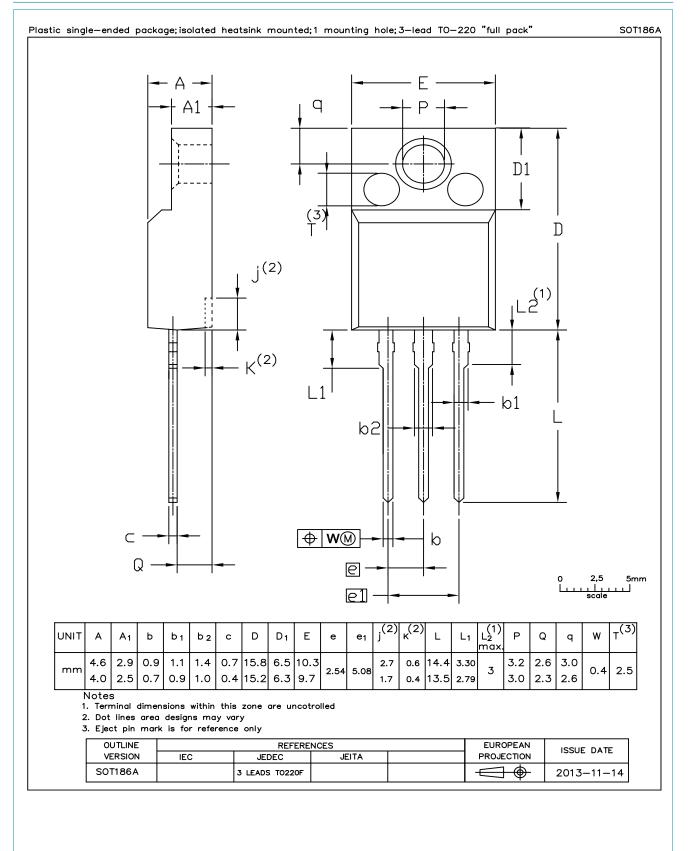


4Q Triac

BT139X-600



12. Package outline



BT139X-600 **Product data sheet**

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13. Legal information

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| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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